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Joint ICTP-IAEA Advanced Workshop on Multi-Scale Modelling for Characterization and Basic Understanding of Radiation Damage Mechanisms in Materials

12 - 23 April 2010

Numerical simulation of transport properties in nuclear fuels : from the atomistic scale to the mesoscopic scale (Part 3)

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Part 3

Numerical simulation of transport properties in nuclear fuels: from the atomistic scale to the mesoscopic scale

Part 3 Outline

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Ab initio modeling of actinide compounds

Illustrations of ab initio studies of nuclear fuels

- Stability of point defects in UO₂
- Atomic transport in UO₂
- Behavior of Xe in UO₂ et UC

Classical Molecular Dynamics (CMD) modeling

Illustrations of CMD studies of nuclear fuels in UO₂

- Formation of defects during displacement cascades
- Influence of grain boundaries on cascades and defects

Conclusion



Illustrations of ab initio studies of nuclear fuels



Illustration 1: Ab initio modeling of the stability of point defects in uranium dioxide UO₂ and uranium carbide UC



Ab initio method for modeling of UO₂ and UC

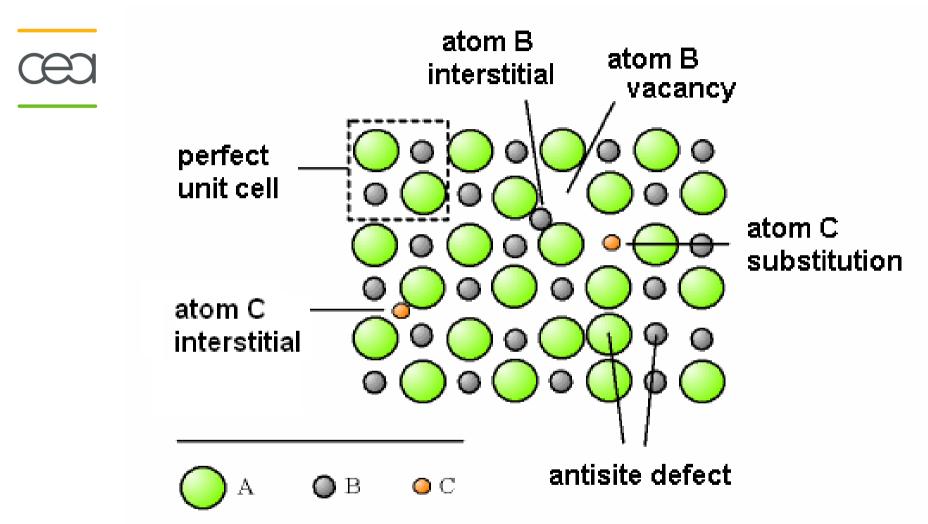
Projector Augmented Wave method (PAW)

- Based on the Density Functional Theory (DFT)
- Plane-Waves as basis functions for valence electrons
- Core electron density taken into account
- Code VASP (http://cms.mpi.univie.ac.at/vasp/)
- Scalar relativistic approximation
- Exchange-correlation functional: **GGA** for **UC**

GGA+U for **UO**₂

- Low cut-off energy of the plane-wave basis: 350 eV for UC, 450 eV for UO₂
- Defects in UC in a 64 atom supercell in UO₂ in a 96 atom supercell
- 4x4x4 Monkhorst-Pack k-point mesh

Point defects

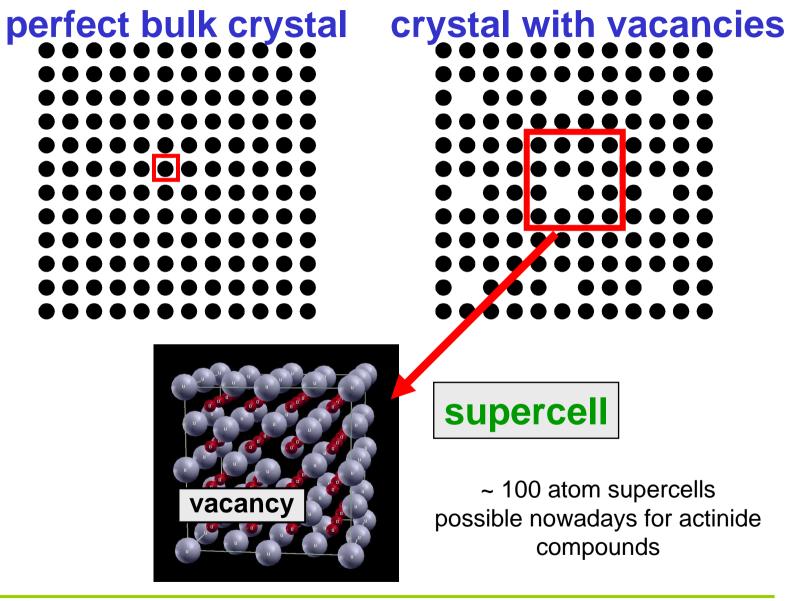


or more complex defects (tri-vacancies, dumbbells, clusters...)



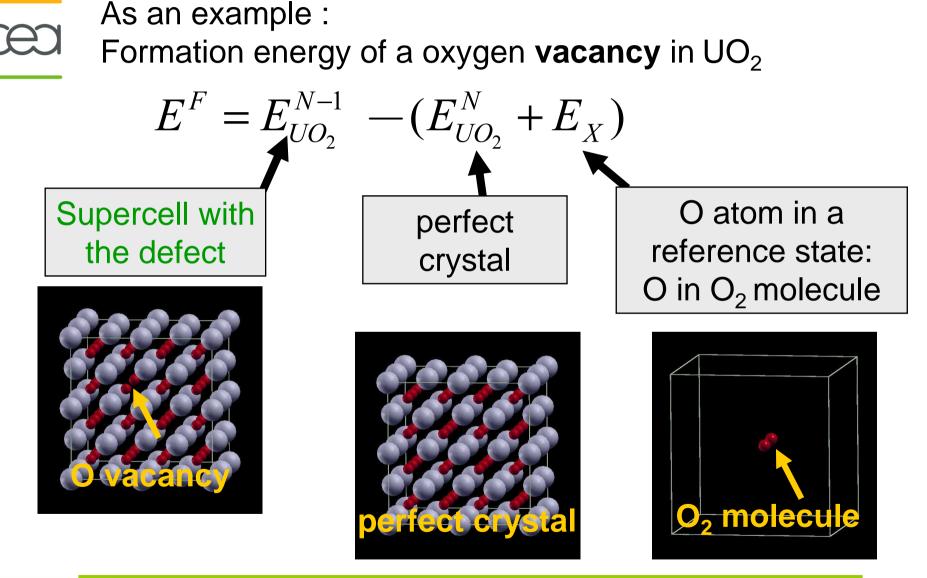
Periodicity: supercell technique







Formation energy of point defects





Point defects in uranium dioxide and carbide

- Vacancies
- Interstitials
 - Frenkel pairs
 - 1 vacancy + 1 interstitial

Schottky defects

- 1 uranium vacancy
- + 2 oxygen vacancies

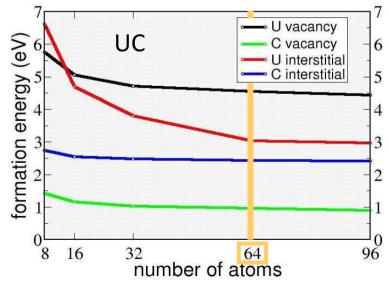
Small vacancy aggregates

Relative stability:

→ Formation energies

Exchange-correlation:GGA (UC) GGA+U (UO_2) Supercellule:64 atoms (UC), 96 atoms (UO_2) Cut-off energy:350 eV (UC), 500 eV (UO_2) k points:4x4x4 gridRelaxation of atomic positions and volume



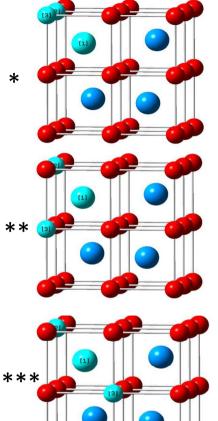




DFT+U formation energies of defects in UO₂



E ^F (eV)	Fluorite	Jahn-Teller
Oxygen interstitial	0.10	0.47
Oxygen vacancy	5.67	6.01
Uranium interstitial	5.38	5.05
Uranium vacancy	10.43	9.87
1 st bound Schottky defect *	3.32	4.07
2 nd bound Schottky defect **	2.55	3.26
3 rd bound Schottky defect ***	2.92	3.41
Isolated Schottky defect	10.66	10.62
Uranium Frenkel pair	15.80	14.62
Oxygen Frenkel pair	5.78	6.48



- Crystal field: moderate effect on formation energies (except I₀)
- > Uranium and oxygen vacancy formation energies > 5 eV.
- Diffusion very likely to occur via Schottky defects
- Ability of vacancies to trap fission gases?

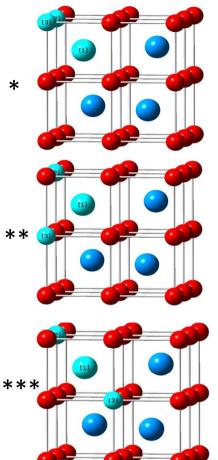
B. Dorado et a., submitted (2010)



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Experimental data H-j. Matzke, J. Chem. Soc., Faraday Trans. 2, 83, 1121 (1987) E^F (O Frenkel pair)= 3.0-4.0 eV, E^F (U Frenkel pair)= 9.5 eV E^F (Schottky)= 6.0-7.0 eV

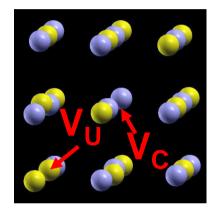
Relative agreement



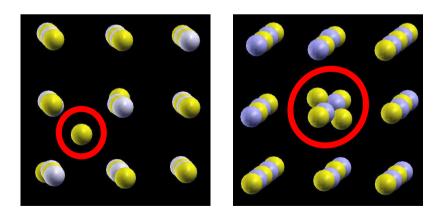
Point defects in UC



- Irradiation damage in UC better accomodated in the carbon sub-lattice
- Weak perturbation of the crystal structure
- Aggregation of U and C vacancies more favorable than isolated vancancies
- « Dumbbell » configuration of interstitials more stable than tetraedral interstitials



Carbon at tetraedral site E^F=2.5 eV



Carbon in a dumbbell <111> E^F=2.2 eV

M. Freyss, Phys. Rev. B 81, 014101 (2010)



Illustrations of ab initio studies of nuclear fuels



Illustration 2: *Ab initio* modeling of migration of defects in UO₂ and UC



Migration energies of point defects in UO₂



Experimentally: activation energies measured and reported in the literature (Auskern 1961, Belle 1969, Marin 1969, Contamin 1972).

- Generally no control of oxygen partial pressure
- No measurement of impurity content
- Dominant migration mechanism remains unknown

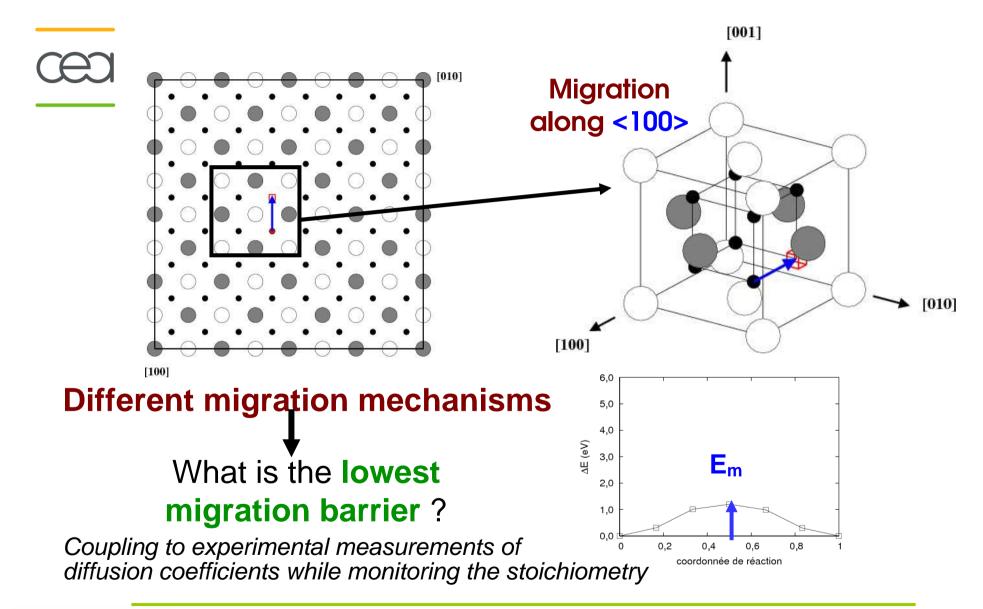
New data for identifying diffusion mechanisms (Garcia *et al.*, Nucl. Mater. (2010) in press. Of presentation. (1)

- J. Nucl. Mater. (2010) in press. Cf presentation 4)
- Theoretically: migration energies calculated with
 - Empirical potentials (Catlow 1977): migration mechanisms
 - Standard DFT (Dorado 2009) : DFT-GGA description of UO₂
 - ♦ DFT+U approximation (Gupta 2010) without the NEB method (migration path not optimized)

Need to use up-to-date methods to determine accurate activation energies for oxygen diffusion. In progress...



Migration energies of point defects in UO₂



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Migration energies: calculation method



Diffusion coefficient
$$D = D_0 \exp\left(-\frac{E_a}{kT}\right) = D_0 \exp\left(-\frac{E_{app}^F + E_m}{kT}\right)$$

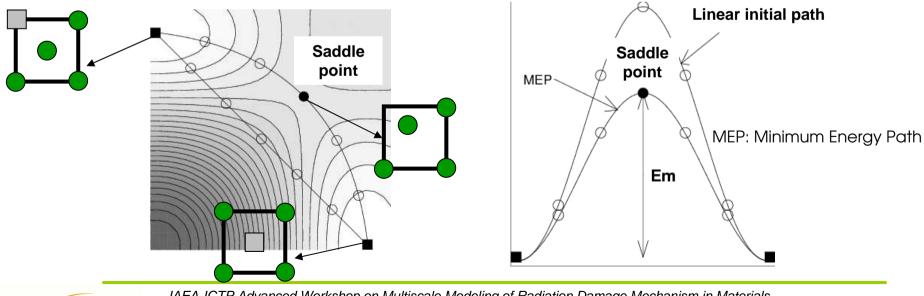
Nudged Elastic Band (NEB)

Determine Minimum Energy Paths for atom migration

 \rightarrow Choice of a start migration path and images along it

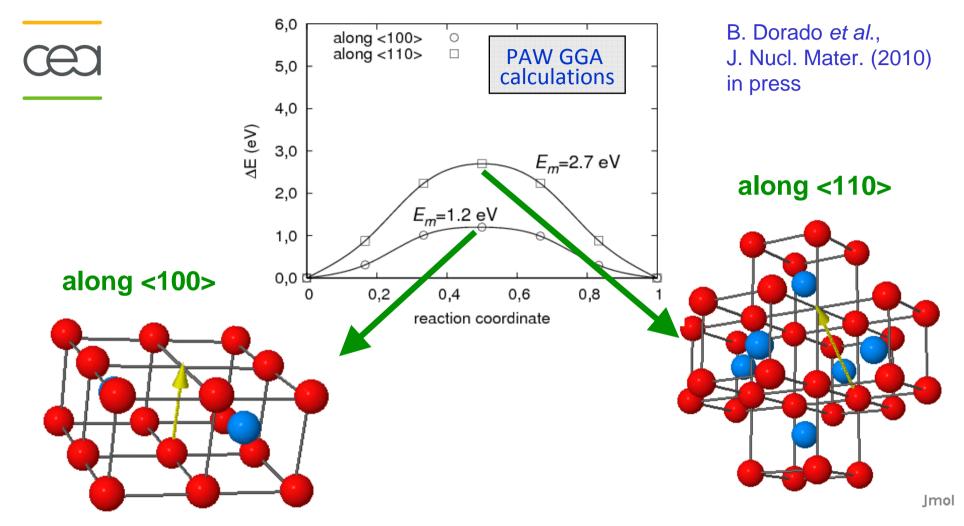
 \rightarrow Atomic relaxation perpendicular to the path

 \rightarrow Allows us to get a physical path (path continuity is ensured)



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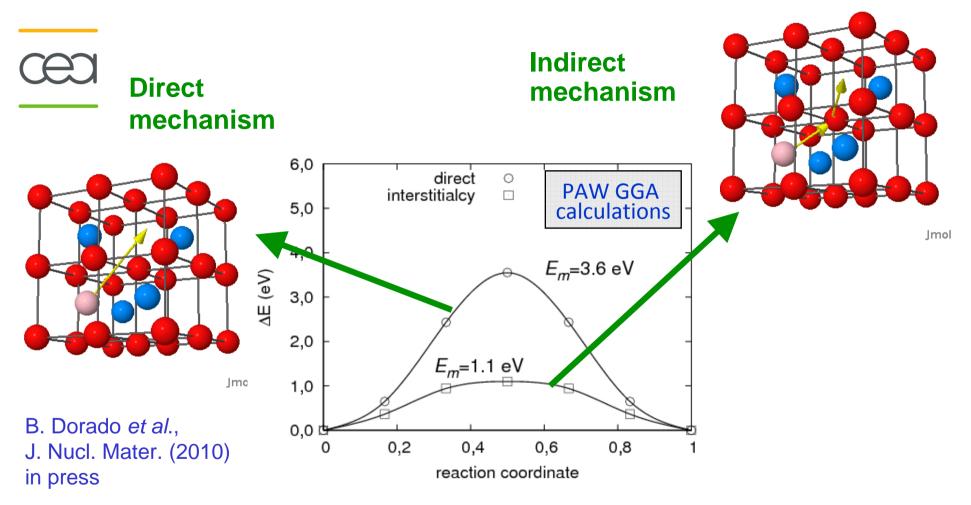
Migration energies: oxygen vacancy



O vacancies are more mobile along the <100> direction than along the <110> direction



Migration energies: oxygen interstitial



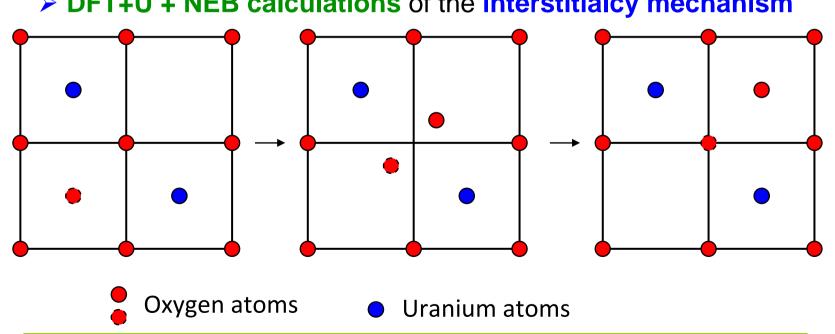
The indirect mechanism is the most favorable mechanism for the migration of O interstitials



Migration energies: oxygen interstitial

|--|

- Electrical conductivity measurements:
 - Control of parameters that affect the material (oxygen) partial pressure and impurity content)
 - Oxygen diffusion occurs via interstitial mechanism
 - Measured activation energy = 0.6 eV





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DFT+U + NEB calculations of the interstitialcy mechanism

Migration energies: oxygen interstitial

 Σ > During the NEB calculation, symmetries are switched off.

> Calculated migration barrier : 0.6 eV \Rightarrow Calculated activation energy $E_a = E^F + E_m = 0.7$ eV (recent measured value: 0.6 eV).

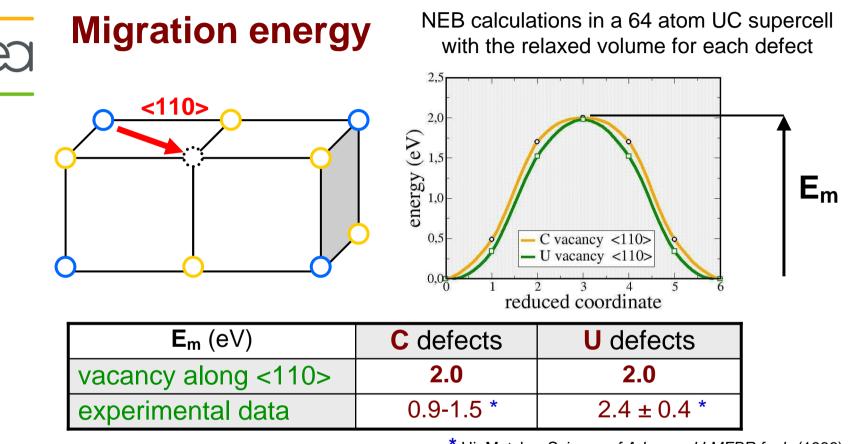
Good agreement between the calculated and experimental activation energies.

> Oxygen diffusion in UO_2 occurs *via* the interstitialcy mechanism.

Other vacancy-assisted mechanisms are currently considered but much higher activation energy (because high formation energy)



Migration in UC: carbon and uranium vacancies



* Hj. Matzke, Science of Advanced LMFBR fuels (1986) Carbon: interstitial mechanisms to be investigated

Same trend in **UN**: $E_{mig}(U) = E_{mig}(N) = 3.5eV$ Not in **UO**₂ : $E_{mig}(U) = 4.4eV > E_{mig}(O) = 1.2eV$ B. Dorado *et al.* J. Nucl. Mater (2009) B. Dorado *et al.* J. Nucl. Mater (2010)

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Illustrations of ab initio studies of nuclear fuels



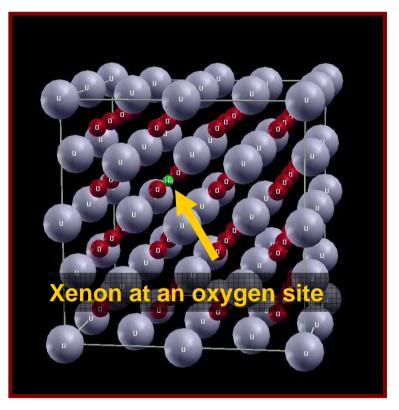
Illustration 3: Modeling of the stability of fission products in UO₂ and UC



Volatile elements in UO_{2:} the case of Xe



- Stability in the lattice
 - interstitial site
 - substitution site
- Incorporation energy
- Solubility
- Structure modifications swelling



GGA or GGA+U calculations Method: PAW / VASP Supercell with 96 atoms

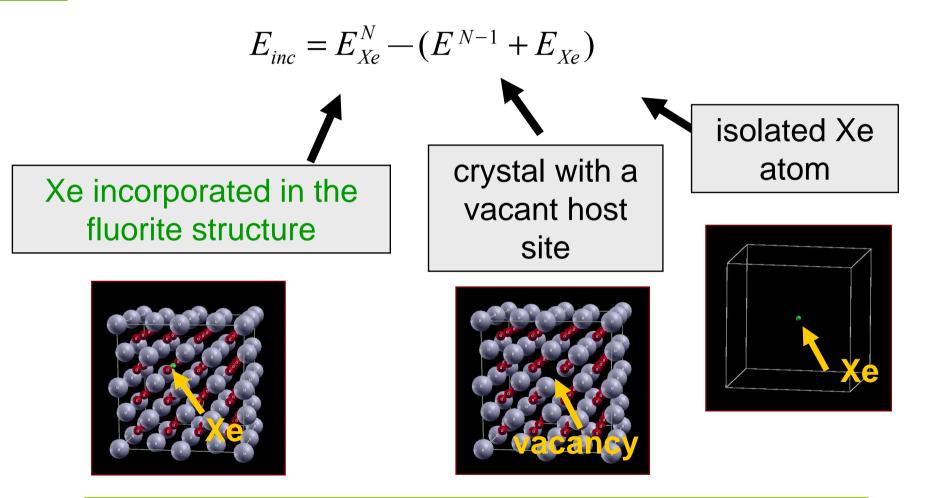
Completed by empirical potential calculations A. Chartier et al., submitted (2010)



Incorporation energy



Energy required to incorporate Xe in a pre-existing vacancy or at an interstitial site:





Xenon incorporation in UO₂ and UC

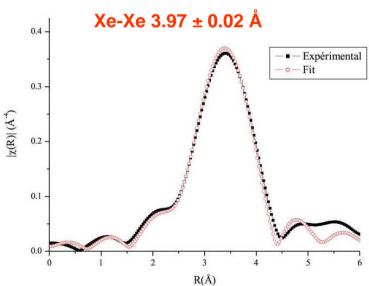
E _{inc} (eV)	site U	site C, O	interst.
UC	4.2	8.2	12.1
UO ₂	5.8	9.1	12.0

Large incorporation energies (> 4 eV) whatever the site: instability of diluted xenon atoms in both UC and UO_2

DFT+U studies of Xe in UO₂: Nerikar *et al.*, J. Phys.: Condens. Matter 21 (2009) 435602 Yu *et al.*, J. Phys.: Condens. Matter 21 (2009) 435401. but problems of metastable states not taken into account

Experimentally characterized in UO₂ by EXAFS and TEM

- \rightarrow Xe implantation, annealing, EXAFS analysis
- → Formation of pressurized Xe clusters



See presentation 4

P. Garcia, P. Martin, G. Carlot, M. Ripert, C. Sabathier et al., J. Nucl. Mater. 352, 136 (2006)



Xenon incorporation in UO₂



Formation of nano-voids and stability of bubbles of xenon in UO₂ A. Chartier *et al.* submitted (2010)

Study with **empirical potentials** (static calculations) fitted on **DFT calculations**

Buckingham potentials for UO_2 and Xe-U and Xe-O interactions (cf. presentation 2). Tang and Toennies potential for Xe-Xe interactions.

	In	corp. energ	ies Einc (eV)
Incorp. sites	Xe(Int)	Xe(Vu)	Xe(Vo)	Xe(S)
DFT	12.0	5.8	9.1	/
emp. pot.	11.9	5.4	9.3	4.2

Higher stability of Xe atoms in Schottky defects (S) compared to substitution or interstitial sites



Xenon in UO₂ : stability of nanovoids



Binding energies of various shapes of voids as a function of the number *p* of Schottky (S) defects.

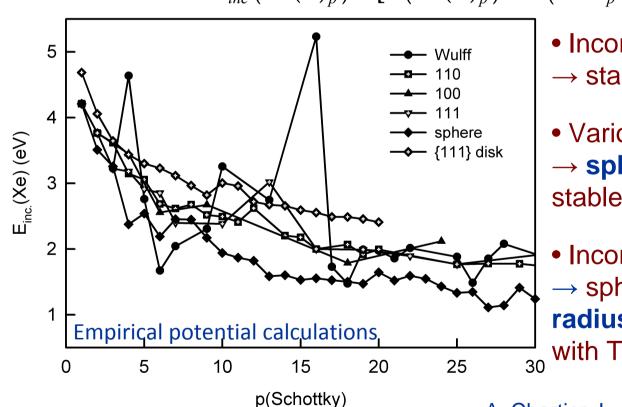
$$E_{binding}(Void_p^S) = [E(Void_p^S) - pE(S)]/p$$



Xenon in UO₂ : incorporation in nanovoids



Xenon incorporation energies (in eV/Xe atom) in different void shapes, as a function of the number *p* of Schottky defects, which contain *p* Xe atoms

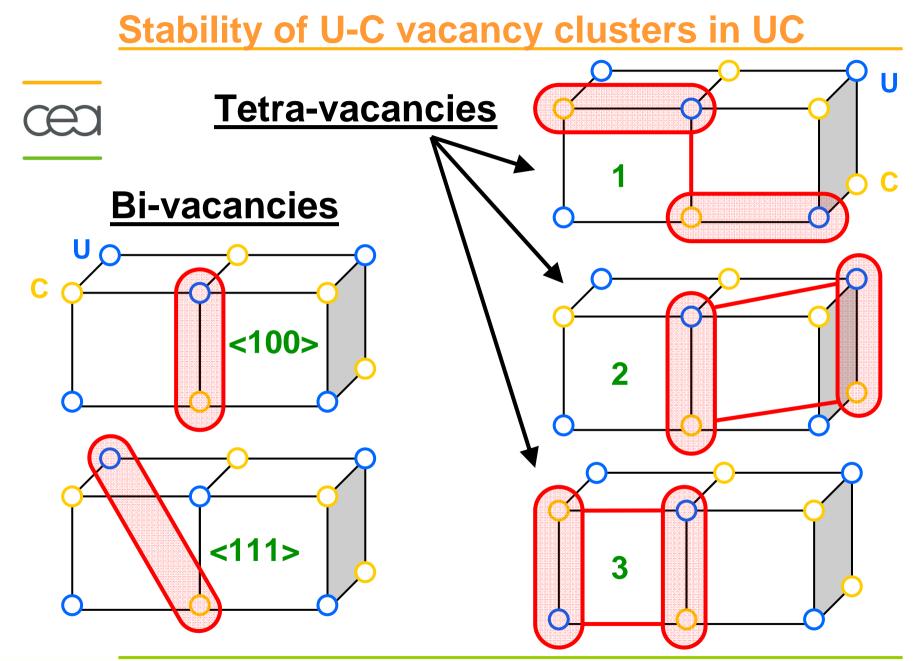


$$E_{inc}(Xe(S)_p) = \left[E(Xe(S)_p) - E(Void_p^S) - pE(Xe_g)\right]/p$$

- Incorp. energy decreases with *p* → stability of xenon clusters
- Various shapes of voids
 → spherical xenon clusters more stable
- Incorp. energy saturates p~20 \rightarrow spherical xenon clusters with radius of 1.3 nm. In agreement with TEM analysis (cf presentation 4)

A. Chartier, L. van Brutzel et al. submitted (2010)







Stability of U-C vacancies in UC: DFT calculations

vacancies	E _F (eV)	E _b (e∨)
monovac U	4.5	/
monovac C	0.8	/
bivac U-C <100>	4.6	- 0.7
bivac U-C <111>	5.3	~ 0
tetravac 1	7.8	- 2.8
tetravac 2	7.3	- 3.3
tetravac 3	8.9	- 1.7

<u>Binding energy</u> **E**_b : Bound vacancies E^F(Vac U-C) *vs.* isolated vacancies E^F(Vac U) + E^F (Vac C) **E**_b < 0: bound vacancies are more stable than isolated vacancies

Possible traps for fission products and helium

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Incorporation of volatile fission products in UC

Ε _{inc} (eV)	Kr	Хе
monovac U	3.6	4.2
monovac C	6.0	8.2
interst. tetra.	10.1	12.1
bivac U-C <100>	2.6	3.2
bivac U-C <111>	3.7	4.3
tetravac 1	2.2	2.4
tetravac 2	1.7	2.2
tetravac 3	2.7	3.4

 $E_{inc} < 0$: stability

Kr and Xe not favorably incorporated: not soluble in UC Most stable at a U substitution site and extended defects, like in UO₂ Larger defects out of scope of ab initio calculations: empirical potentials

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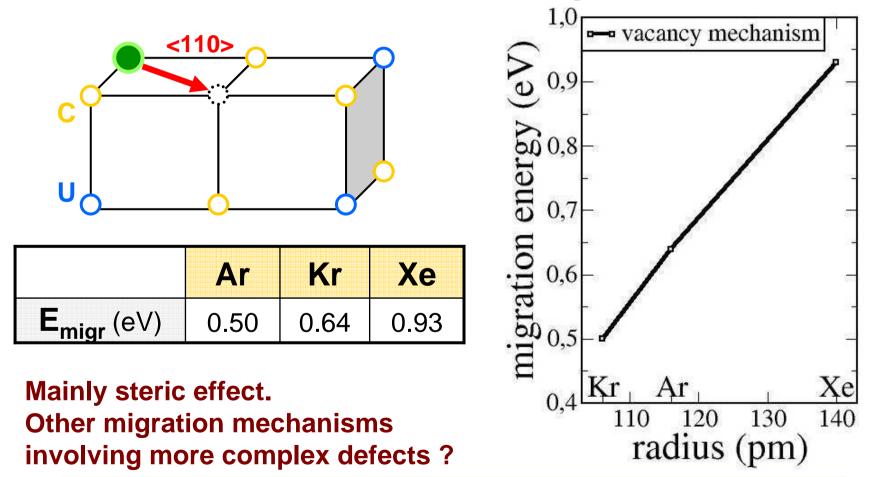
Migration of volatile fission products in UC

Nudge Elastic Band (NEB) calculations in a 64 atom UC supercell



Only one migration path investigated so far:

U substitution site \rightarrow U vacancy







Classical Molecular Dynamics Simulations of displacement cascades in UO₂



Empirical potentials and molecular dynamics

Principle

- Interatomic interactions described by analytical potential giving the energy as a function of separation distance
- Parametrized on experimental or ab initio data
- Potential form different for each system type
- Parameters different for each system
- Simulates evolution of systems in time
- Based on statistical mechanics. Calculation in a statistical ensemble (example: N, V, T constant)
- Calculations at finite temperature

Advantages / Disadvantages

- Quick ⇒ Investigation of large systems / long times
- Existing data necessary for parametrization
- Non transferable: potentials only valid in situation close to those used for parametrization
- No description of electronic structure

Cf presentation 2

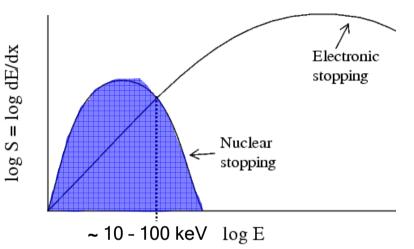


CMD simulation of cascades in UO₂



Slowing down of fission products

 ⇒ Simulation of displacement cascades generated by U atom
 Description of elastic collisions



Empirical pair potential for UO₂ [1]

- relatively simple: rigid ion potential U^{3,2+} et O^{1,6-}
- without charge transfer: no description of electronic changes
- satisfactory for UO₂ defect migration/formation properties

[1] N. D. Morelon, et al., Phil. Mag. 83, 1533 (2003)



Illustrations of CMD studies of nuclear fuels



Illustration 1 : formation of defects during displacement cascades



Formation of defects during displacement cascades in UO₂



Fluorite structure UO₂

Up to 68×68×68 unit cells (3 million atoms), stabilized 20 ps at 300K and 0 GPa

Energy pulse given to an atom (Primary Knock-on Atom PKA) \rightarrow 1 to 80 keV

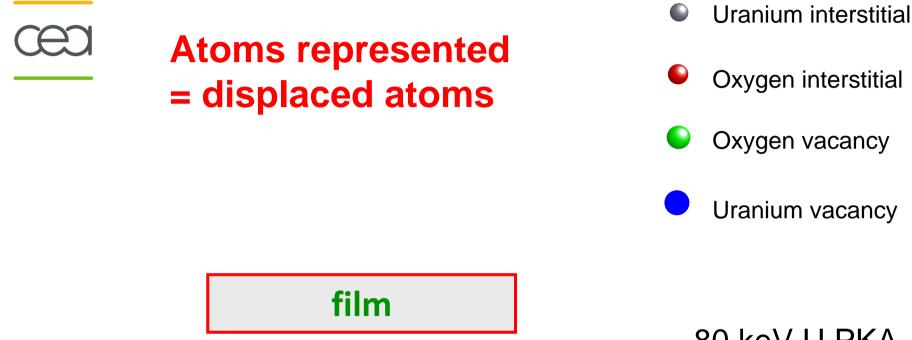
- Cascades simulated with constant N,V,~E
- Temperature control at the boundaries of the box (3 Å)
- Periodic boundary conditions
- Variable time steps
- Statistical approach to interpret results: several cascades performed in the same conditions with different locations and directions of the PKA.



Single cascade: successive steps of defect formation and recombination
Cascade overlaps: saturation of defect formation



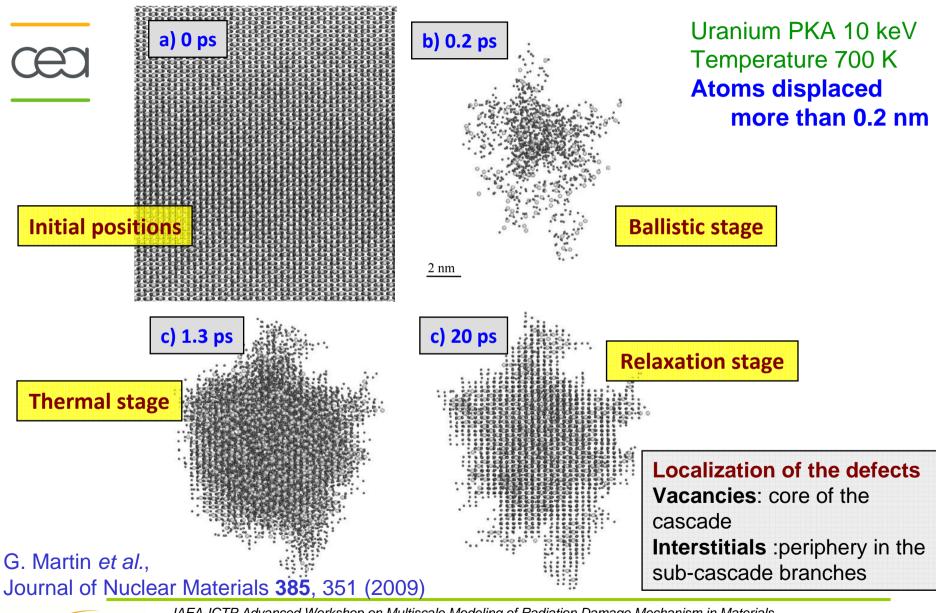
Displacement cascade in UO₂ with a 80 keV PKA



80 keV U PKA 68x68x68 cell 300 K



Successive steps of a displacement cascade in UO₂



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Number of defects after a cascade in UO₂



The total number of defects created **increases** with the energy of the PKA

High recombination rate: a displaced atoms finds an equivalent crystal site.

No amorphisation of UO_2 .

The recombination rate for uranium increases rapidly with temperature.

G. Martin *et al.*, J. Nucl. Mater. **385**, 351 (2009) L. Van Brutzel *et al.*, Phys. Rev. B **78**, 024111 (2008)



Overlap of cascades in UO₂

Study of primary damage produced by a flux of energetic particles

Cascade overlap within the same simulation box \rightarrow response of the material to increasing damage levels

Sequence of cascades: **new PKA every 25 ps** Energy of the uranium PKA: **10 keV** Different directions and locations of the PKA Uranium Total duration of the simulation: 350 ps Temperature **700 K**



PKA 2

Overlap of cascades in UO₂



film



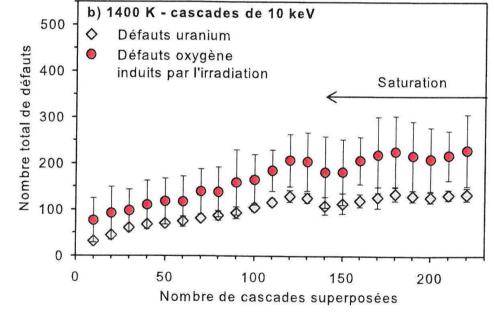
Damage production after displacement cascades in UO₂



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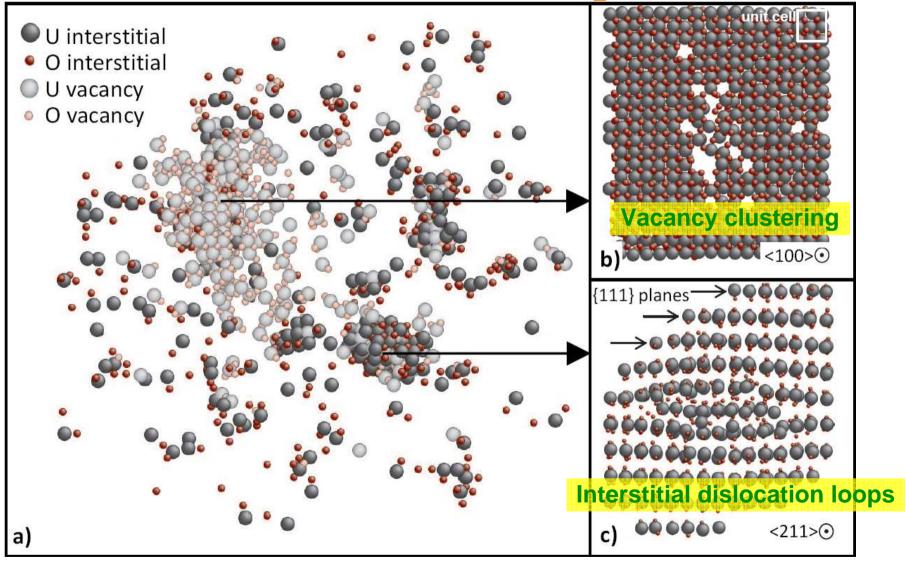
Total number of defects generated first increases (linearly) with the number of cascades, then increases slower to reach **saturation**

G. Martin *et al.*, to be published (2010)



Saturation is reached for a smaller total number of defects when the temperature is higher

Damage production after displacement cascades in UO₂





Illustrations of CMD studies of nuclear fuels



Illustration 2 : Grain boundaries influence in UO₂

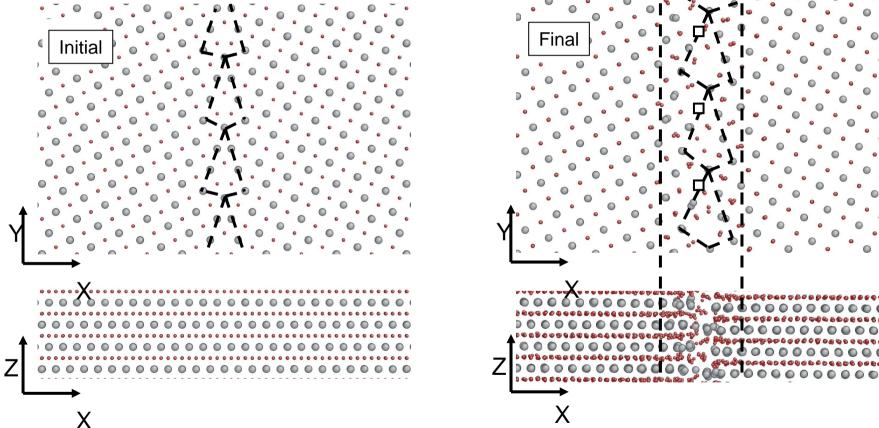


Grain boundaries influence in UO₂

(L. van Brutzel, CEA Saclay)

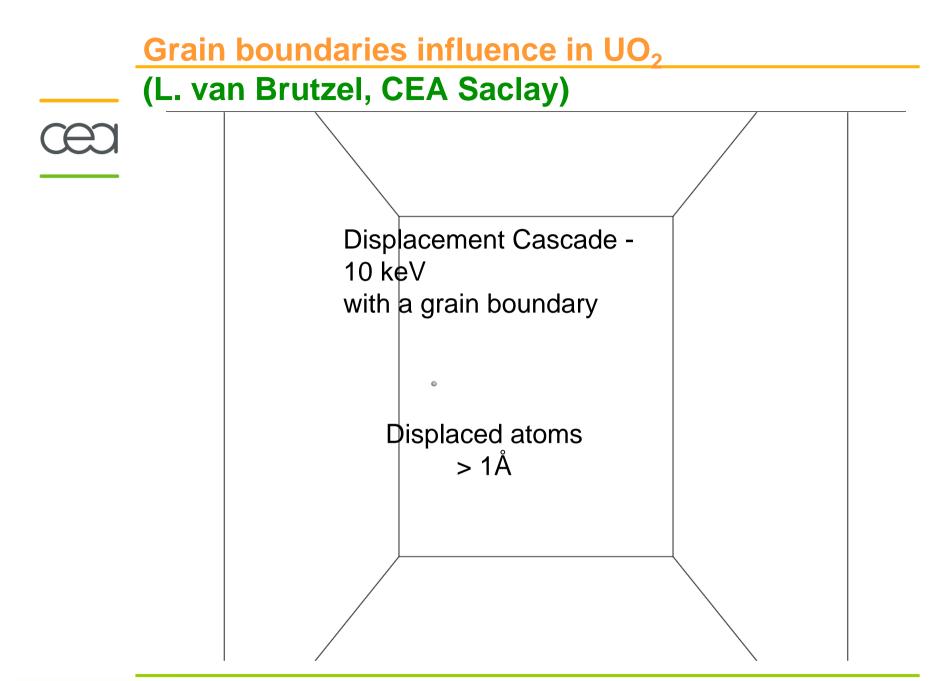


Evolution of the grain boundary Σ5 at 300K during relaxation (constant N, P, T)

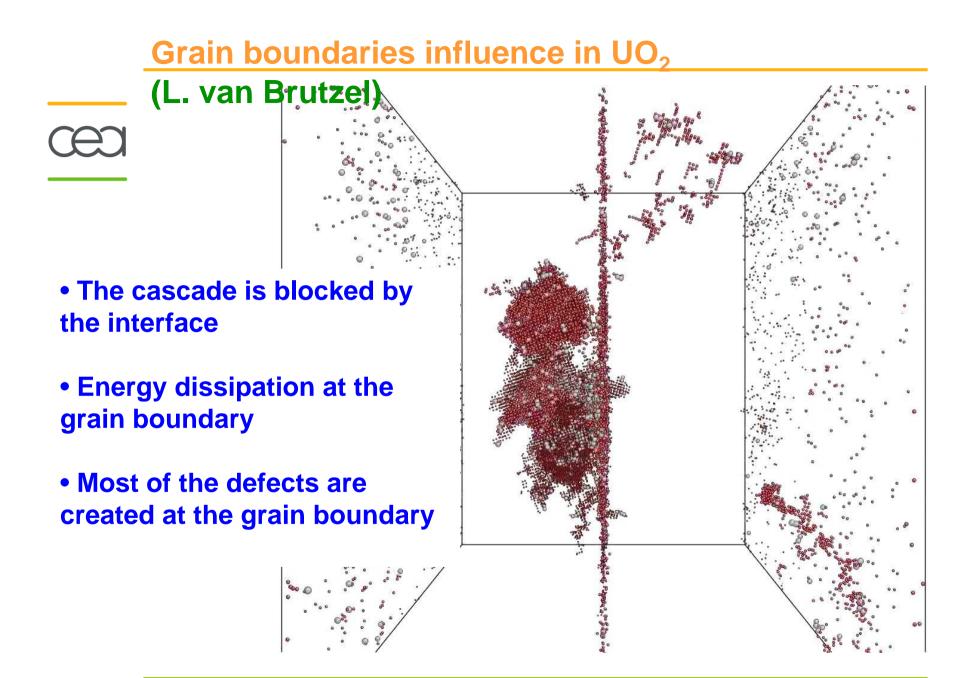


Pattern of Schottky defects = experimental observations











Part 3 Conclusion

Application of atomistic calculations to nuclear fuels

- Ab initio calculations and CMD simulations are powerful tools
 - to identify atomic scale mechanisms
 - to generate quantitative data
- Studies of phenomena difficult to access experimentally
- Support experiments and microscopic modeling techniques

Challenges for the future

- Better ab initio approximation of strong correlation in UO₂
- Better ab initio description of Van der Waals interactions to model rare gases in the material
- Development of empirical potentials for rare gases & fission products
- Better integration of *atomistic* calculations in the **multiscale** modeling of nuclear fuels (KMC, performance code...)



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